CT scan data from Appareo package #2





Experimental Details

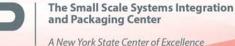
- Two CT scans of Appareo package #2 were performed.
 - First CT scan with field of view (FOV) that covered the entire memory package (provided voxel size resolution of 37 μ m).
 - Second CT scan zoomed in on \sim half the die with full row of wire bonds in FOV (provided voxel size resolution of $17\mu m$).
- CT scans were performed at 110 120 kV tube voltage, 110 μA current, spot mode 0.
- Cu filter along with a collimator, was used during x-ray exposure.
- Total exposure time for two CT scans was ~ 2.75 hrs.
- Defects within the package were identified and snap shots of such defects were taken along 3 axes (orthogonal





Summary and Conclusions

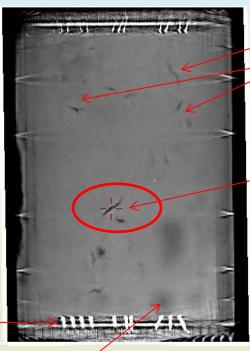
- Appareo package #2 contains 4 stacked dies, 2 on each side of the Cu paddle.
- Molding compound of this package, was found to be severely damaged probably from high-temp/fire. Such extreme heat/fire can also damage the chip circuitry.
- Widespread cracks, voids, separation areas, were detected in the entire mold compound.
- Most cracks seem to go through the mold thickness, and reach die top with circuitry. These exposed die areas could possibly have damaged the chip circuitry.
- Large areas of separation between mold and die top, were detected on both sides of the package. Some of these areas are close enough to wire bonds to cause their delamination /dislodging. Such wire defects could not be detected in the CT scan data due to resolution limitation and image artefacts created by high x-ray absorption Au wires.



Low-mag CT data from side 1: 3D slice views

Frontal (x,z)

Frontal View



Cracks in the mold

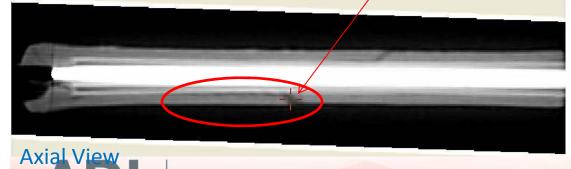
Molding compound crack on surface appears to go down to the die top with circuitry

Saggital View



Wire bonds

This separation between mold/die top, is close to wire bonds to possibly dislodge/delaminate them.



Dense materials appear bright Light materials, voids/separation appear darker in CT snap shots.

Notice red-cross hair on a defect in each slice image. These 3 slice views correspond to image of that defect in three axes.

Several cracks and separation areas are detected in the molding compound on both sides of the package

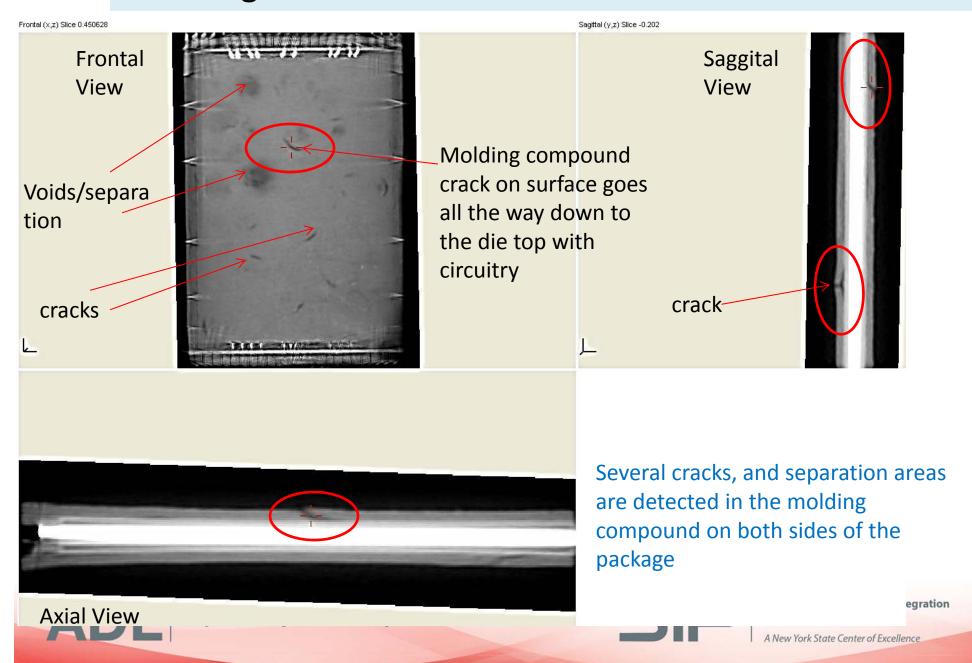


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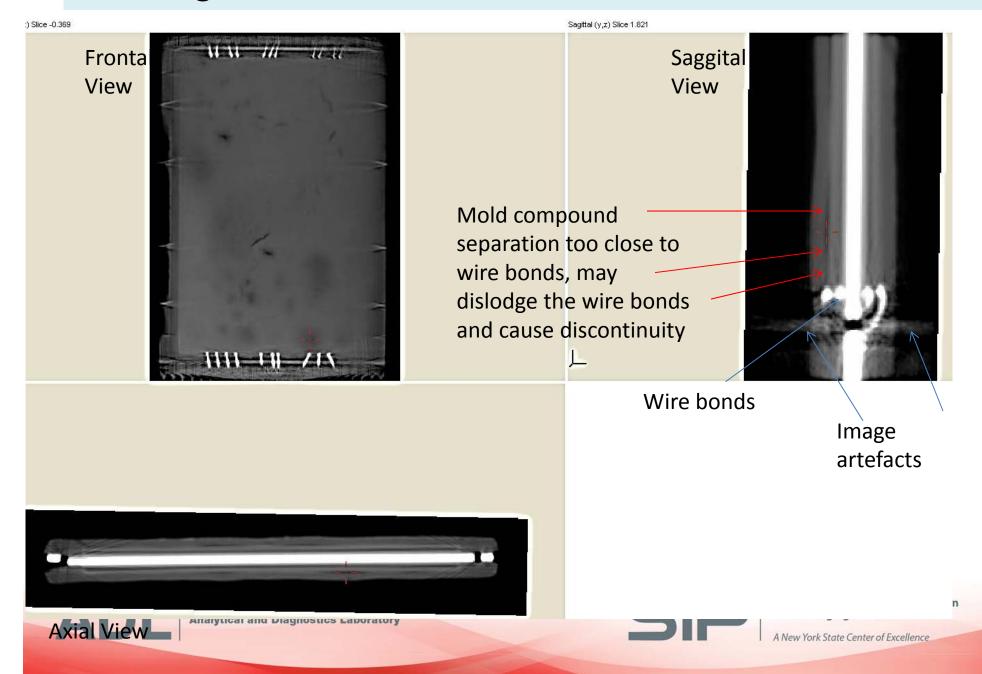
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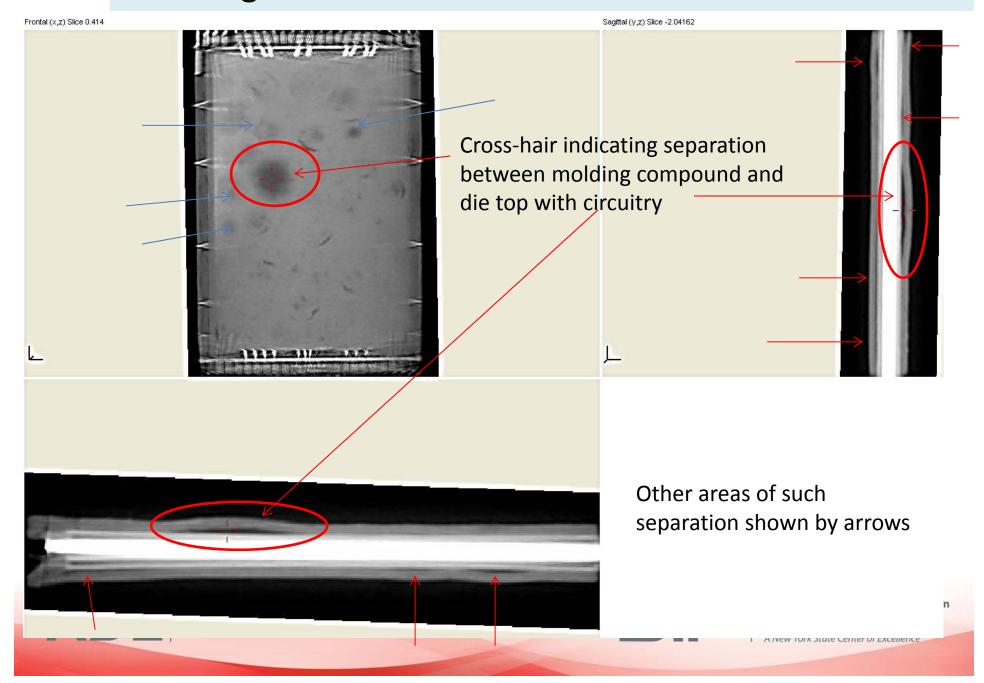
Low-mag CT data from side 2: 3D slice views



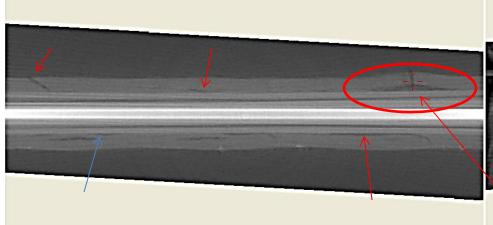
Low-mag CT data from side 1: 3D slice views

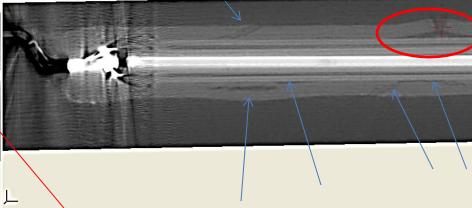


Low-mag CT data from side 2: 3D slice views



Higher-mag CT data, side 2: 3D slice views

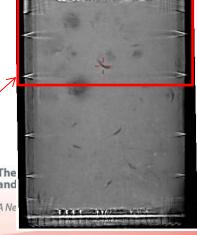






Cross-hair indicating separation/crack between molding compound and die top

Other areas of such separation/cracks shown by arrows

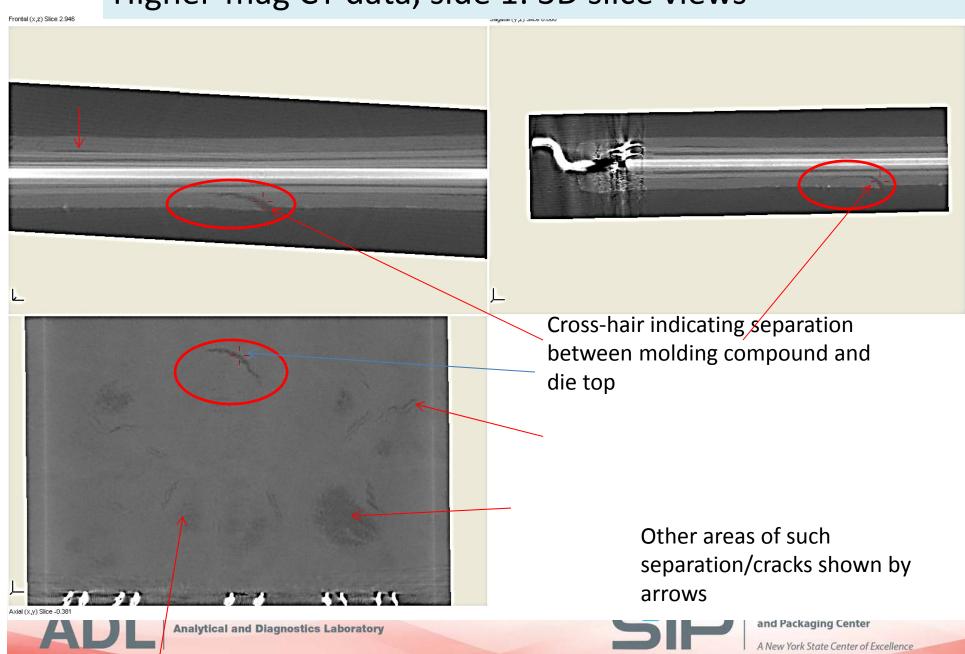




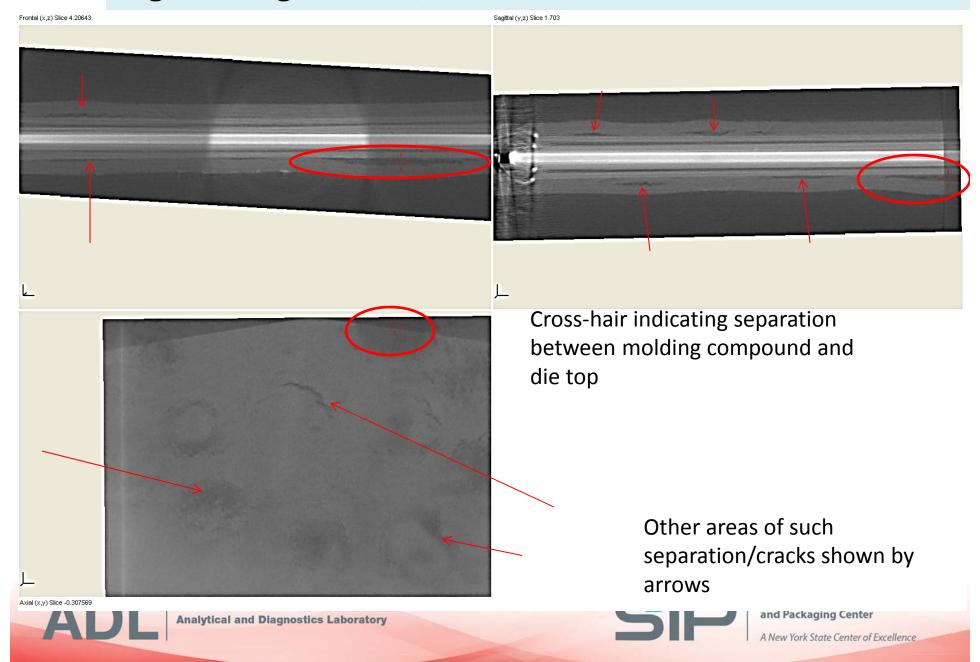
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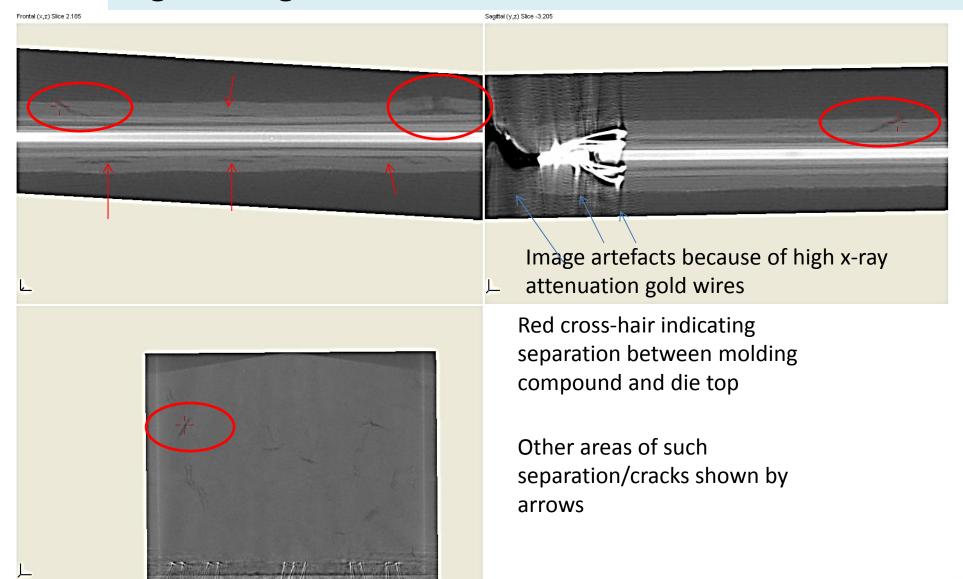
Higher-mag CT data, side 1: 3D slice views



Higher-mag CT data, side 1: 3D slice views



Higher-mag CT data, side 2: 3D slice views



Axial (x,y) Slice 0.492

SIP

Summary and Conclusions

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